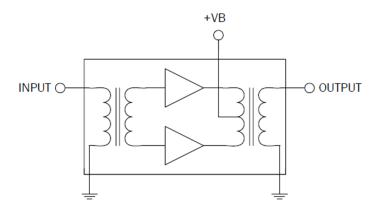


R1005250L

25dB Reverse Hybrid 5MHz to 100MHz (Low Current)

The R1005250L is a hybrid reverse amplifier. The part employs a silicon die. It has extremely low distortion and superior return loss performance. The part also provides optimal reliability with low noise and is well suited for 5MHz to 100MHz CATV amplifiers for reverse channel systems.



Ordering Information

R1005250L Box with 50 pieces

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone)	65	dBmV
DC Supply Over-Voltage (5 minutes)	30	V
Storage Temperature	-40 to +100	°C
Operating Mounting Base Temperature	-30 to +100	°C



Package: SOT-115J

Features

- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Low Noise
- Unconditionally Stable Under All Terminations
- 25.5dB Typical Gain at 100MHz
- 140mA Max. at 24VDC

Applications

 5MHz to 100MHz CATV Amplifier For Reverse Channel Systems



Caution! ESD sensitive device.



RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2011/65/EU.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implie



Nominal Operating Parameters

Parameter	Specification		Unit	Constitue		
	Min	Тур	Max	Unit	Condition	
General Performance					$V+ = 24V$; $T_{MB} = 30^{\circ}C$; $Z_{S} = Z_{L} = 75\Omega$	
Power Gain	24.8	25.3	25.8	dB	f = 5MHz	
	24.6	25.5		dB	f = 100MHz	
Slope ^[1]	-0.2	0.2	0.5	dB	f = 5MHz to 100MHz	
Flatness of Frequency Response			±0.3	dB	f = 5MHz to 100MHz (peak to valley)	
Input Return Loss	-20			dB	f = 5MHz to 100MHz	
Output Return Loss	-20			dB	T = SMHZ TO TOUMHZ	
Noise Figure		3.4	3.6	dB	f = 100MHz	
Total Current Consumption (DC)	125.0	133	140.0	mA		
Distortion Data 5MHz to 100MHz					$V+ = 24V$; $T_{MB} = 30^{\circ}C$; $Z_{S} = Z_{L} = 75\Omega$	
СТВ			-69	dBc	7 ch flat; $V_0 = 50 \text{dBmV}^{[2]}$	
			-65	dBc	12 ch flat; $V_0 = 50 \text{dBmV}^{[3]}$	
XMOD			-59	dBc	7 ch flat; $V_0 = 50 \text{dBmV}^{[2]}$	
XMOD			-55	dBc	12 ch flat; $V_0 = 50 \text{dBmV}^{[3]}$	
CSO			-70	dBc	7 ch flat; $V_0 = 50 dBmV^{[2]}$	
C30			-70	dBc	12 ch flat; $V_0 = 50 \text{dBmV}^{[3]}$	

^{1.} The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.

Composite Second Order (CSO) - The CSO parameter (both sum and difference products) is defined by the NCTA.

Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.

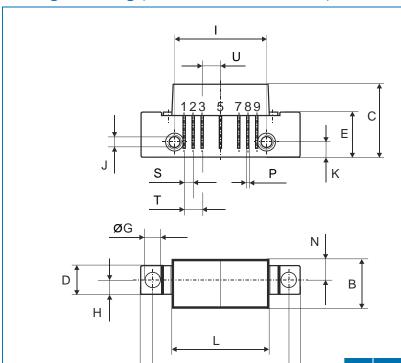
Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.

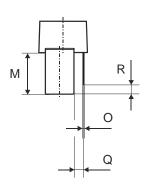
^{2. 7} channels, NTSC frequency raster: T7 - T13 (7.0MHz to 43MHz), +50dBmV flat output level.

^{3. 12} channels, NTSC frequency raster: T7 - T13 (7.0MHz to 43MHz), 2 - 6 (55.25MHz to 83.25MHz), +50dBmV flat output level.



Package Drawing (Dimensions in millimeters)





0 5 10mm لسلسيا scale

Notes:

European Projection





Pin	Name
1	Input
2-3	GND
4	
5	+VB
6	
7-8	GND
9	Output

	Nominal	Min	Max
Α	44,6 ^{± 0,2}	44,4	44,8
В	13,6 ^{± 0,2}	13,4	13,8
С	20,4 ^{± 0,5}	19,9	20,9
D	8 ^{± 0,15}	7,85	8,15
Е	12,6 ^{± 0,15}	12,45	12,75
F	38,1 ^{± 0,2}	37,9	38,3
G	4 +0,2 / -0,05	3,95	4,2
Н	4 ^{± 0,2}	3,8	4,2
1	25,4 ^{± 0,2}	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ± 0,2	4,0	4,4
L	27,2 ^{± 0,2}	27,0	27,4
M	11,6 ^{± 0,5}	11,1	12,1
N	5,8 ^{± 0,4}	5,4	6,2
0	0,25 ^{± 0,02}	0,23	0,27
Р	0,45 ^{± 0,03}	0,42	0,48
Q	2,54 ^{± 0,3}	2,24	2,84
R	2,54 ^{± 0,5}	2,04	3,04
S	2,54 ^{± 0,25}	2,29	2,79
Т	5,08 ^{± 0,25}	4,83	5,33
U	5,08 ^{± 0,25}	4,83	5,33